Internally Compensated, High Performance Operational Amplifier

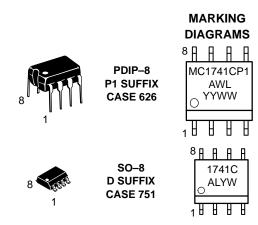
The MC1741C was designed for use as a summing amplifier, integrator, or amplifier with operating characteristics as a function of the external feedback components.

- No Frequency Compensation Required
- Short Circuit Protection
- Offset Voltage Null Capability
- Wide Common Mode and Differential Voltage Ranges
- Low Power Consumption
- No Latch Up

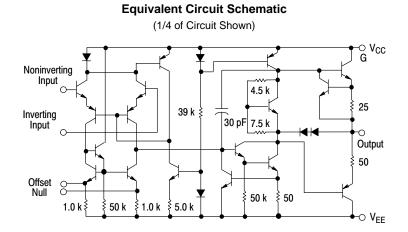


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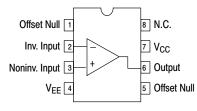
http://onsemi.com



A = Assembly Location WL, L = Wafer Lot YY, Y = Year WW, W = Work Week



PIN CONNECTIONS



(Top View)

ORDERING INFORMATION

| Device | Package | Shipping |
|------------|---------|------------------|
| MC1741CD | SO–8 | 98 Units/Rail |
| MC1741CDR2 | SO–8 | 2500 Tape & Reel |
| MC1741CP1 | PDIP-8 | 50 Units/Rail |

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MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Power Supply Voltage | V _{CC} , V _{EE} | ±18 | Vdc |
| Input Differential Voltage | V _{ID} | ±30 | V |
| Input Common Mode Voltage (Note 1.) | V _{ICM} | ±15 | V |
| Output Short Circuit Duration (Note 2.) | t _{SC} | Continuous | - |
| Operating Ambient Temperature Range | T _A | 0 to +70 | °C |
| Storage Temperature Range | T _{stg} | -55 to +125 | °C |

For supply voltages less than +15 V, the absolute maximum input voltage is equal to the supply voltage.
 Supply voltage equal to or less than 15 V.

ELECTRICAL CHARACTERISTICS (V_{CC} = +15 V, V_{EE} = -15 V, T_A = 25° C, unless otherwise noted.)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|--|------------------------------|------------|------------------|-----|-----------------|
| Input Offset Voltage ($R_S \le 10 \text{ k}$) | V _{IO} | - | 2.0 | 6.0 | mV |
| Input Offset Current | l _{IO} | - | 20 | 200 | nA |
| Input Bias Current | I _{IB} | - | 80 | 500 | nA |
| Input Resistance | r _i | 0.3 | 2.0 | - | MΩ |
| Input Capacitance | Ci | - | 1.4 | - | pF |
| Offset Voltage Adjustment Range | V _{IOR} | - | ±15 | - | mV |
| Common Mode Input Voltage Range | V _{ICR} | ±12 | ±13 | - | V |
| Large Signal Voltage Gain (V_O = ± 10 V, R _L ≥ 2.0 k) | A _{VOL} | 20 | 200 | - | V/mV |
| Output Resistance | r _o | - | 75 | - | Ω |
| Common Mode Rejection ($R_S \le 10 \text{ k}$) | CMR | 70 | 90 | - | dB |
| Supply Voltage Rejection ($R_S \le 10 \text{ k}$) | PSR | 75 | _ | - | dB |
| Output Voltage Swing $(R_L \ge 10 \text{ k})$ $(R_L \ge 2.0 \text{ k})$ | Vo | ±12 ±10 | ±14 ±13 | | V |
| Output Short Circuit Current | I _{SC} | - | 20 | - | mA |
| Supply Current | ۱ _D | - | 1.7 | 2.8 | mA |
| Power Consumption | P _C | - | 50 | 85 | mW |
| $ \begin{array}{l} \mbox{Transient Response (Unity Gain, Noninverting)} \\ (V_I = 20 \mbox{ mV, } R_L \geq 2.0 \mbox{ k, } C_L \leq 100 \mbox{ pF}) \mbox{ Rise Time} \\ (V_I = 20 \mbox{ mV, } R_L \geq 2.0 \mbox{ k, } C_L \leq 100 \mbox{ pF}) \mbox{ Overshoot} \\ (V_I = 10 \mbox{ V, } R_L \geq 2.0 \mbox{ k, } C_L \leq 100 \mbox{ pF}) \mbox{ Slew Rate} \end{array} $ | t _{TLH} os SR | | 0.3 15 0.5 | | μs % V/μs |

ELECTRICAL CHARACTERISTICS (V_{CC} = +15 V, V_{EE} = -15 V, T_A = T_{low} to T_{high} , unless otherwise noted.)*

| Characteristic | Symbol | Min | Тур | Мах | Unit |
|--|------------------|-----|-----|-----|------|
| Input Offset Voltage ($R_S \le 10 \text{ k}\Omega$) | V _{IO} | - | - | 7.5 | mV |
| Input Offset Current ($T_A = 0^\circ$ to +70°C) | I _{IO} | - | - | 300 | nA |
| Input Bias Current ($T_A = 0^\circ$ to +70°C) | I _{IB} | - | - | 800 | nA |
| Supply Voltage Rejection ($R_S \le 10 \text{ k}$) | PSR | 75 | - | - | dB |
| Output Voltage Swing ($R_L \ge 2.0 \text{ k}$) | V _O | ±10 | ±13 | - | V |
| Large Signal Voltage Gain (R _L \ge 2.0 k, V _O = ±10 V) | A _{VOL} | 15 | - | - | V/mV |

* $T_{low} = 0^{\circ}C$ $T_{high} = 70^{\circ}C$

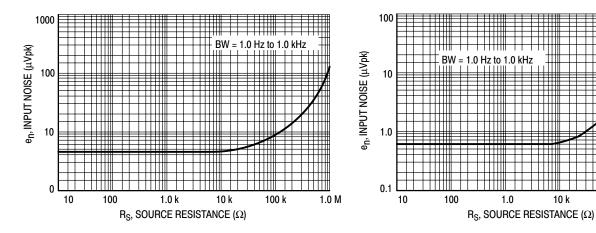


Figure 1. Burst Noise versus Source Resistance

Figure 2. RMS Noise versus Source Resistance

10 k

100 k

1.0 M

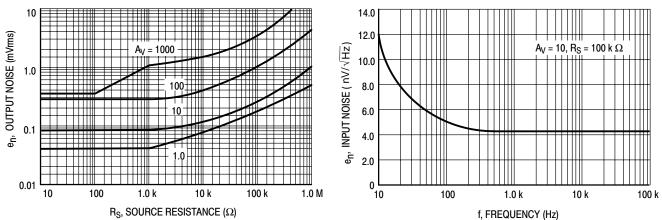
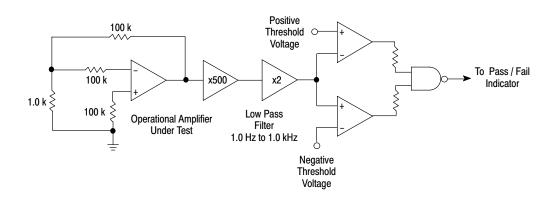


Figure 3. Output Noise versus Source Resistance





Unlike conventional peak reading or RMS meters, this system was especially designed to provide the quick response time essential to burst (popcorn) noise testing.

The test time employed is 10 sec and the 20 mV peak limit refers to the operational amplifier input thus eliminating errors in the closed loop gain factor of the operational amplifier.

Figure 5. Burst Noise Test Circuit

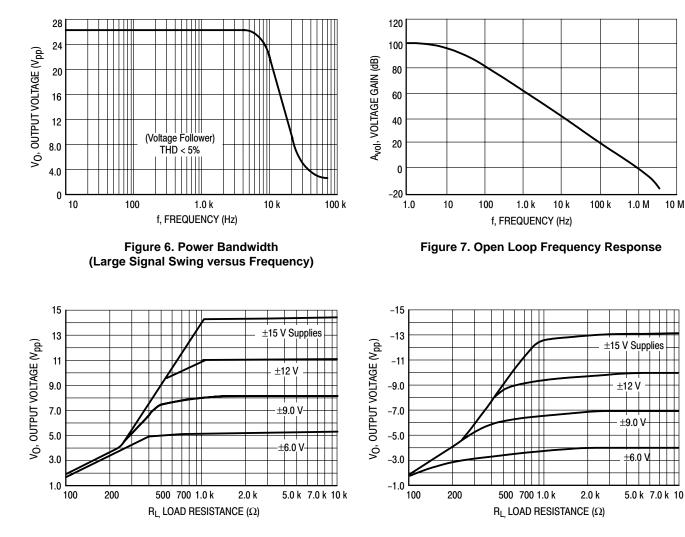


Figure 8. Positive Output Voltage Swing versus Load Resistance

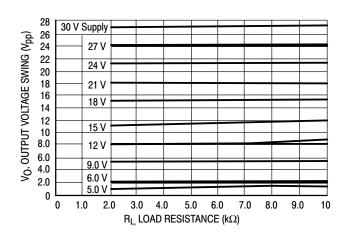
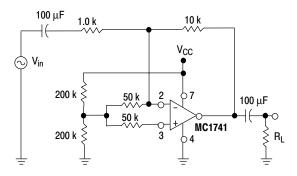
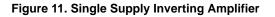


Figure 10. Output Voltage Swing versus Load Resistance (Single Supply Operation)

Figure 9. Negative Output Voltage Swing versus Load Resistance





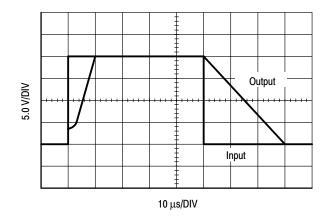
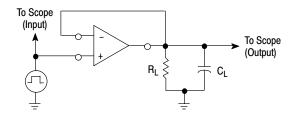
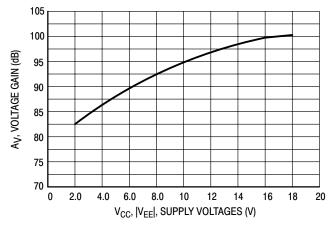


Figure 12. Noninverting Pulse Response



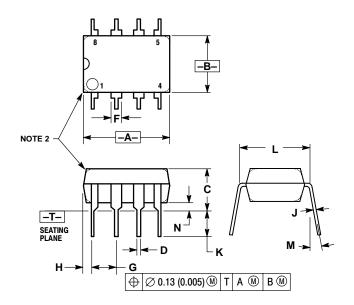






PACKAGE DIMENSIONS

PDIP-8 **P1 SUFFIX** CASE 626-05 ISSUE K

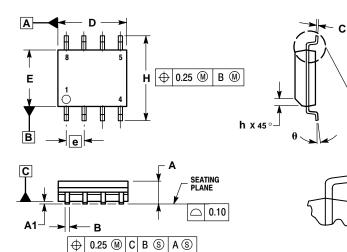


NOTES: 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL. 2. PACKAGE CONTOUR OPTIONAL (ROUND OR CONTER CONTERPOL

SQUARE CONTOINT OF TOTAL (HOUND OF SQUARE CORNERS). 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

| | MILLIMETERS | | INCHES | |
|-----|-------------|----------|--------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 9.40 | 10.16 | 0.370 | 0.400 |
| В | 6.10 | 6.60 | 0.240 | 0.260 |
| C | 3.94 | 4.45 | 0.155 | 0.175 |
| D | 0.38 | 0.51 | 0.015 | 0.020 |
| F | 1.02 | 1.78 | 0.040 | 0.070 |
| G | 2.54 | 2.54 BSC | | BSC |
| н | 0.76 | 1.27 | 0.030 | 0.050 |
| J | 0.20 | 0.30 | 0.008 | 0.012 |
| K | 2.92 | 3.43 | 0.115 | 0.135 |
| L | 7.62 BSC | | 0.300 | BSC |
| М | | 10° | | 10° |
| N | 0.76 | 1.01 | 0.030 | 0.040 |

SO-8 **D SUFFIX** CASE 751-06 ISSUE T



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS ARE IN MILLIMETER.
3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION. CONDITION.

| | MILLIMETERS | | |
|-----|-------------|------|--|
| DIM | MIN MAX | | |
| Α | 1.35 | 1.75 | |
| A1 | 0.10 | 0.25 | |
| В | 0.35 | 0.49 | |
| С | 0.19 | 0.25 | |
| D | 4.80 | 5.00 | |
| E | 3.80 | 4.00 | |
| е | 1.27 BSC | | |
| н | 5.80 | 6.20 | |
| h | 0.25 | 0.50 | |
| L | 0.40 | 1.25 | |
| θ | 0 ° | 7 ° | |

<u>Notes</u>

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